

# Small Signal Schottky diode

# RB751V-40S2

## Description

Planar silicon Schottky barrier diode encapsulated in a SOD-323 plastic SMD package.

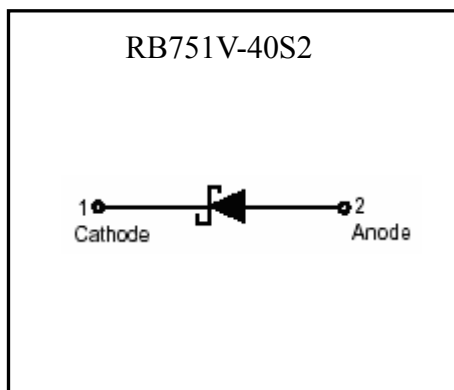
## Features

- Small surface mounting type SC-76/SOD323
- Low reverse current and low forward voltage
- High reliability
- Pb-free lead plating and halogen-free package

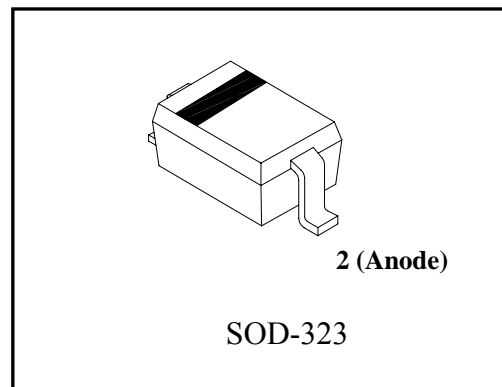
## Applications

Low current rectification and high speed switching

## Symbol



## Outline



## Ordering Information

Device	Package	Shipping	Marking
RB751V-40S2-0-T1-G	SOD-323 (Pb-free lead plating and halogen-free package)	3000 pcs / Tape & Reel	5E



### Absolute Maximum Ratings

- Maximum Temperatures
  - Storage Temperature  $T_{stg}$ ..... -40~+125°C
  - Junction Temperature  $T_j$ ..... +125°C
- Maximum Voltages and Currents ( $T_a=25^\circ\text{C}$ )
  - Peak Reverse Voltage  $V_{RM}$ ..... 40 V
  - DC Reverse Voltage  $V_R$ ..... 30 V
  - Mean Rectifying Current  $I_o$ ..... 30 mA
  - Peak Forward Surge Current  $I_{FSM}$ .....200 mA

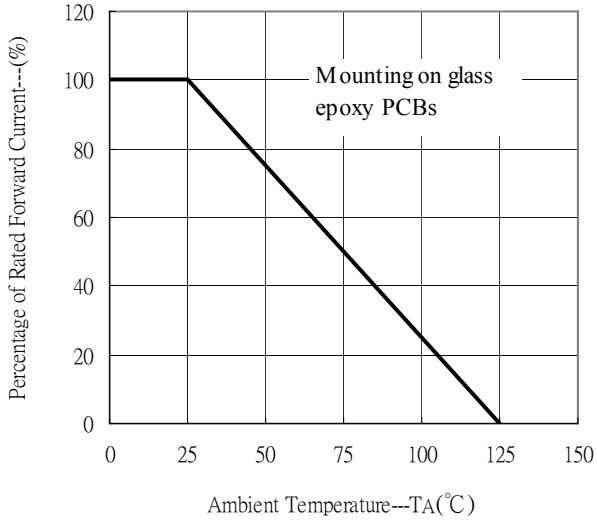
### Characteristics ( $T_a=25^\circ\text{C}$ )

Characteristic	Symbol	Condition	Min.	Typ	Max.	Unit
Forward Voltage	$V_F$	$I_F=1\text{mA}$	-	-	370	mV
Reverse Leakage Current	$I_R$	$V_R=30\text{V}$	-	-	0.5	$\mu\text{A}$
Capacitance Between Terminals	$C_T$	$V_R=1\text{V}, f=1\text{MHz}$	-	2	-	pF

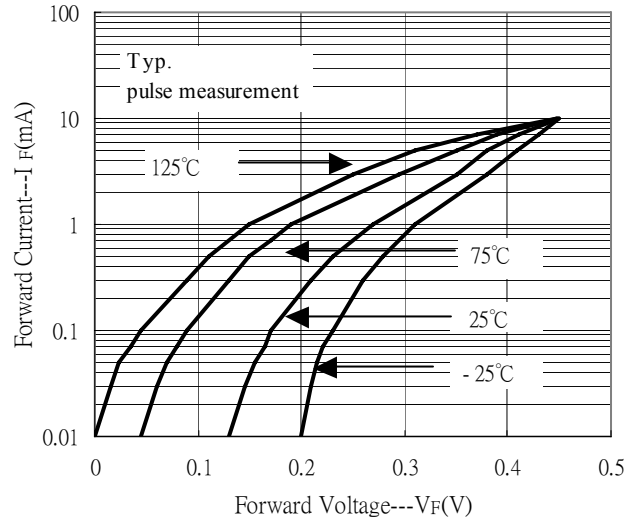


### Characteristic Curves

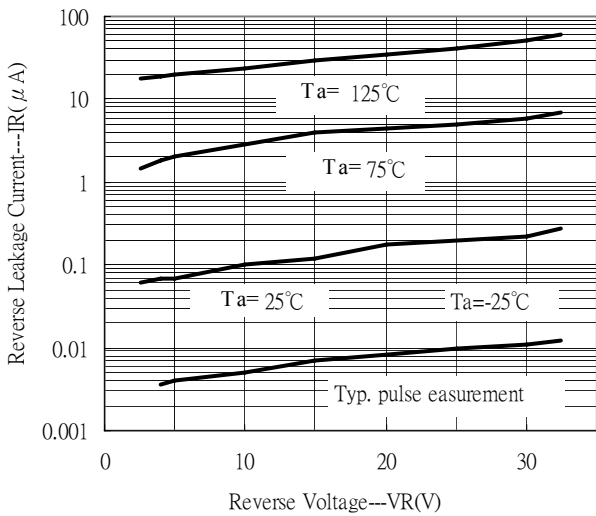
Forward Current Derating Curve



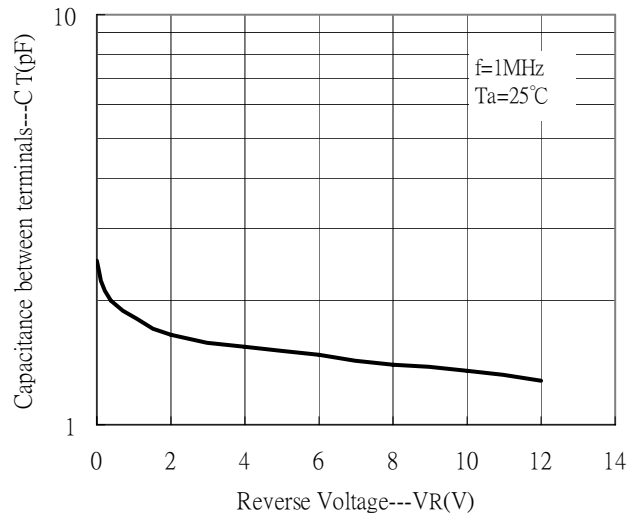
Forward Current vs Forward Voltage



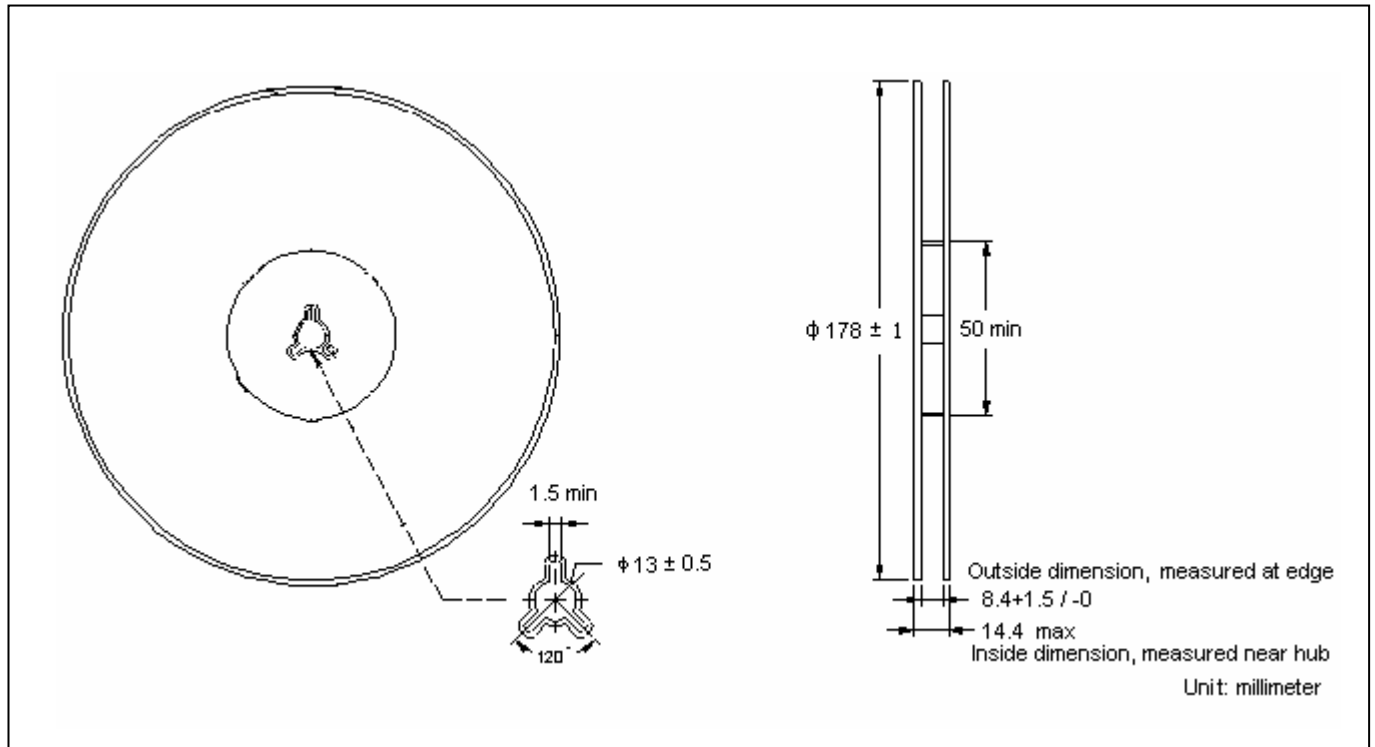
Reverse Leakage Current vs Reverse Voltage



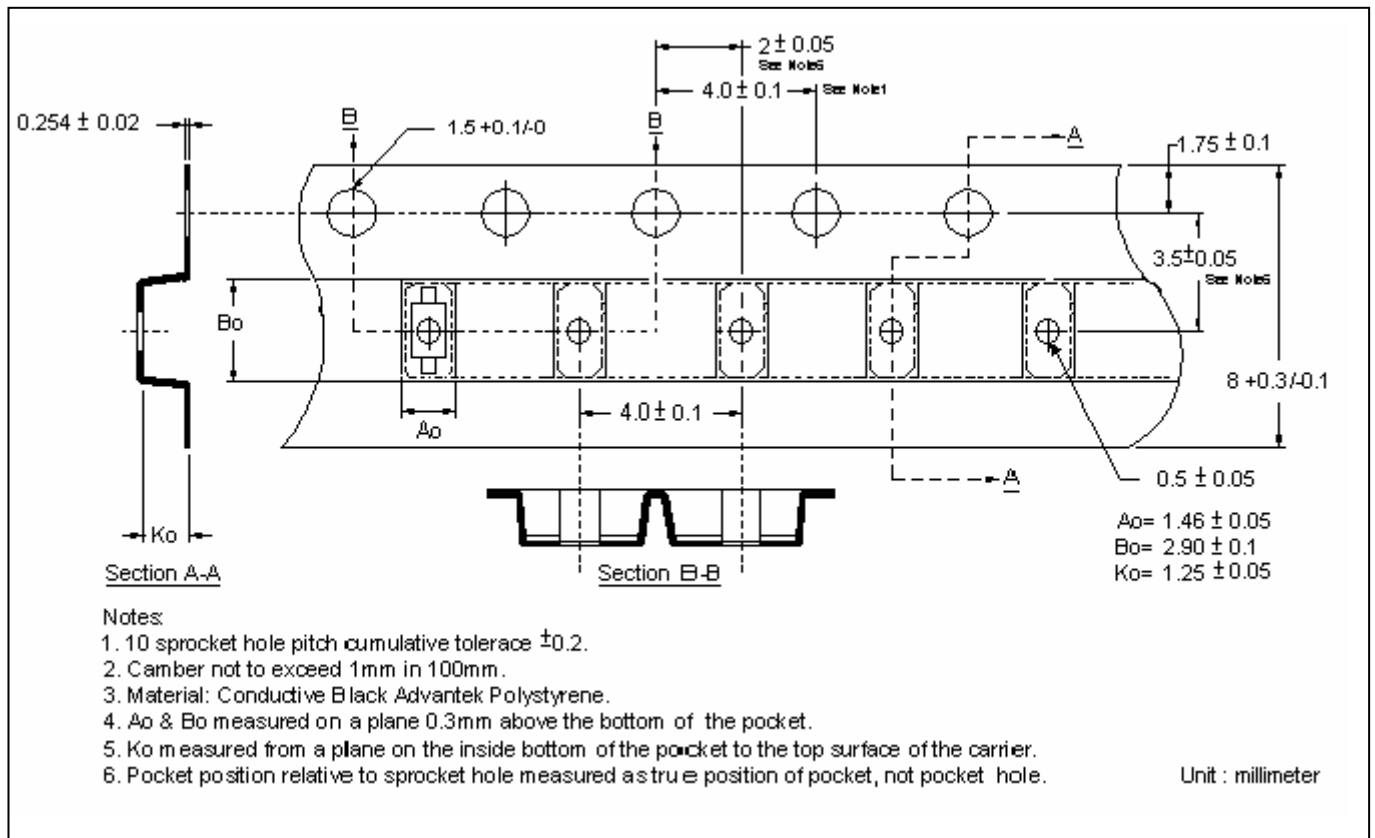
Capacitance vs Reverse Voltage



### Reel Dimension



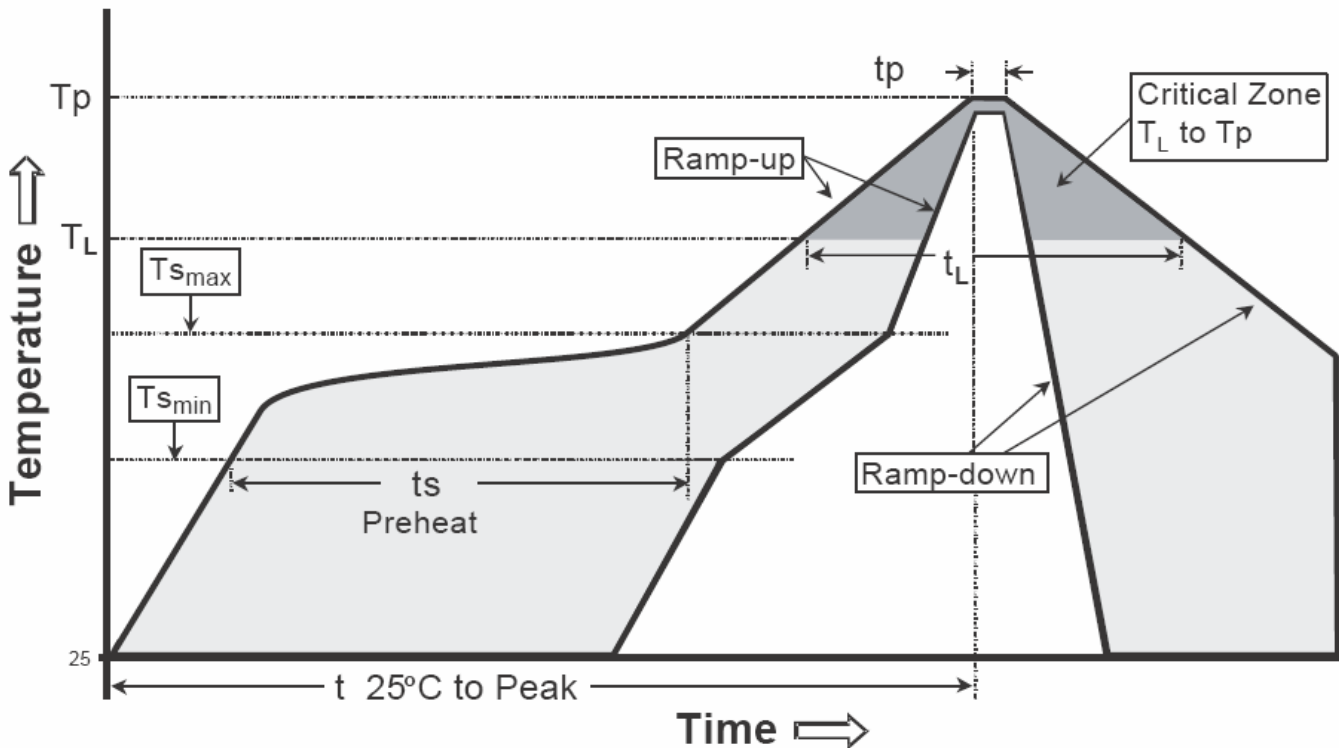
### Carrier Tape Dimension



**Recommended wave soldering condition**

Product	Peak Temperature	Soldering Time
Pb-free devices	260 +0/-5 °C	5 +1/-1 seconds

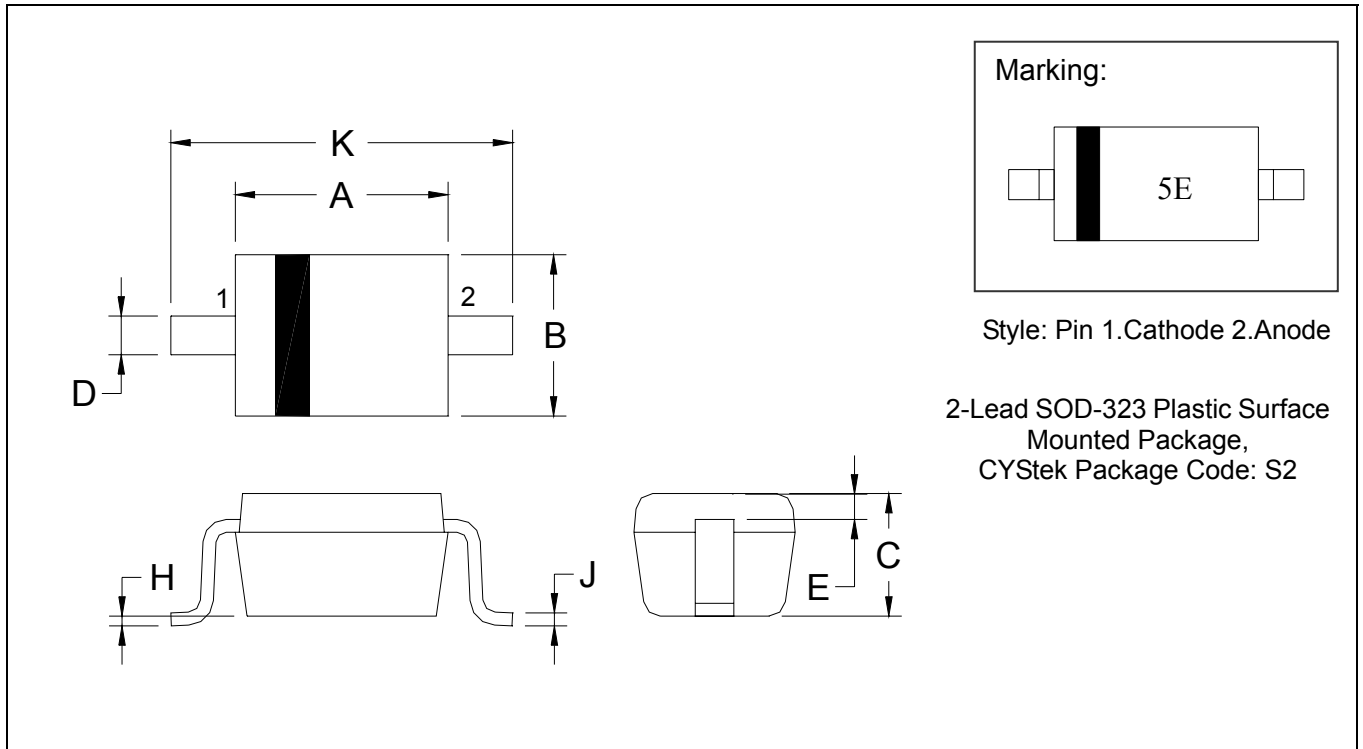
**Recommended temperature profile for IR reflow**



Profile feature	Sn-Pb eutectic Assembly	Pb-free Assembly
Average ramp-up rate (T <sub>smax</sub> to T <sub>p</sub> )	3°C/second max.	3°C/second max.
Preheat		
-Temperature Min(T <sub>s min</sub> )	100°C	150°C
-Temperature Max(T <sub>s max</sub> )	150°C	200°C
-Time(t <sub>s min</sub> to t <sub>s max</sub> )	60-120 seconds	60-180 seconds
Time maintained above:		
-Temperature (T <sub>L</sub> )	183°C	217°C
- Time (t <sub>L</sub> )	60-150 seconds	60-150 seconds
Peak Temperature(T <sub>P</sub> )	240 +0/-5 °C	260 +0/-5 °C
Time within 5°C of actual peak temperature(tp)	10-30 seconds	20-40 seconds
Ramp down rate	6°C/second max.	6°C/second max.
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.

Note : All temperatures refer to topside of the package, measured on the package body surface.

**SOD-323 Dimension**



\*: Typical

DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	0.0630	0.0709	1.60	1.80	E	0.0060 REF		0.15 REF	
B	0.0453	0.0531	1.15	1.35	H	0.0000	0.0040	0.00	0.10
C	0.0315	0.0394	0.80	1.00	J	0.0035	0.0070	0.089	0.177
D	0.0098	0.0157	0.25	0.40	K	0.0906	0.1063	2.30	2.70

Notes: 1.Controlling dimension : millimeters.  
 2.Lead thickness specified per L/F drawing with solder plating.  
 3.If there is any question with packing specification or packing method, please contact your local CYStek sales office.

**Material:**

- Lead: Pure tin plated.
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0.

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